COMPLIANT



Vishay General Semiconductor

Ultrafast Avalanche SMD Rectifier



DO-214AC (SMA)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	1.5 A			
V _{RRM}	200 V to 600 V			
I _{FSM}	30 A			
I _R	1.0 μΑ			
V_{F}	1.4 V			
t _{rr}	75 ns			
E _R	20 mJ			
T _J max.	150 °C			

FEATURES

- · Low profile package
- · Ideal for automated placement
- Glass passivated junction
- · Low reverse current
- · Soft recovery characteristics
- Ultrafast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification of power supply, inverters, converters and freewheeling diodes for consumer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214AC (SMA)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	BYG20D	BYG20G	BYG20J	UNIT	
Device marking code		BYG20D	BYG20G	BYG20J		
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	٧	
Average forward current	I _{F(AV)}	1.5			Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30			А	
Pulse energy in avalanche mode, non repetitive (inductive load switch off) $I_{(BR)R} = 1 \text{ A, } T_J = 25 \text{ °C}$	E _R	20			mJ	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	BYG20D	BYG20G	BYG20J	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	at $I_F = 1 A$ $I_F = 1.5 A$	T _J = 25 °C	V _F		1.3 1.4		V
Maximum DC reverse current	at V _R = V _{RRM}	T _J = 25 °C T _J = 100 °C	I _R	1 10		μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	75		ns	

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	BYG20D BYG20G BYG20J		UNIT	
Typical thermal resistance - junction lead $T_L = const.$	$R_{ heta JL}$	25		°C/W	
Typical thermal resistance - junction ambient	$R_{ hetaJA}$	150 ⁽¹⁾ 125 ⁽²⁾ 100 ⁽³⁾		°C/W	

Notes:

- (1) Mounted on epoxy-glass hard tissue
- (2) Mounted on epoxy-glass hard tissue, 50 mm^2 35 μm Cu
- (3) Mounted on Al-oxide-ceramic (Al₂O₃), 50 mm² 35 μm Cu

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
BYG20D-E3/TR	0.064	TR	1800	7" diameter plastic tape and reel		
BYG20D-E3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel		
BYG20DHE3/TR (1)	0.064	TR	1800	7" diameter plastic tape and reel		
BYG20DHE3/TR3 (1)	0.064	TR3	7500	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

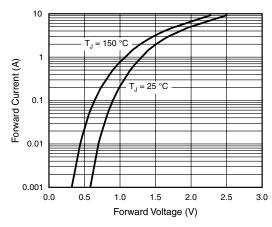


Figure 1. Forward Current vs. Forward Voltage

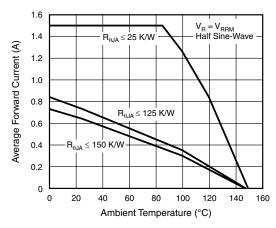


Figure 2. Max. Average Forward Current vs. Ambient Temperature



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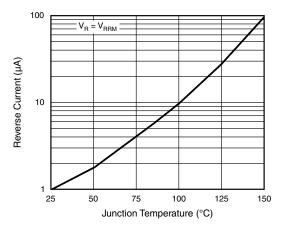


Figure 3. Reverse Current vs. Junction Temperature

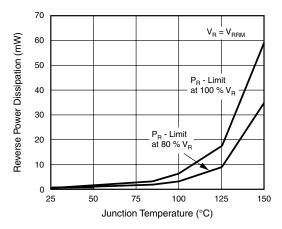


Figure 4. Max. Reverse Power Dissipation vs. Junction Temperature

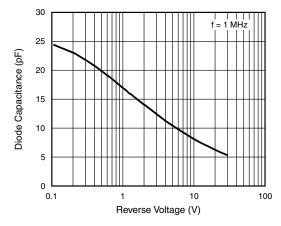


Figure 5. Diode Capacitance vs. Reverse Voltage

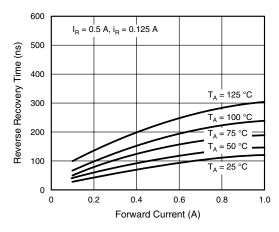


Figure 6. Reverse Recovery Time vs. Forward Current

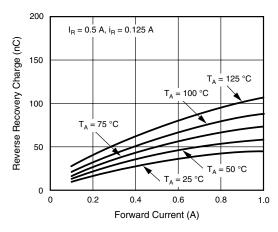


Figure 7. Reverse Recovery Charge vs. Forward Current

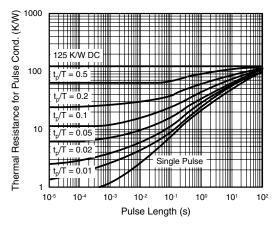


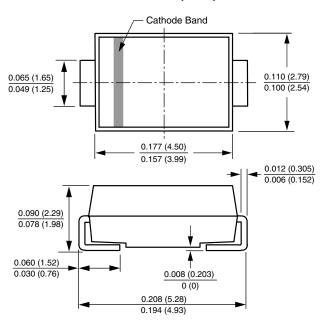
Figure 8. Thermal Response

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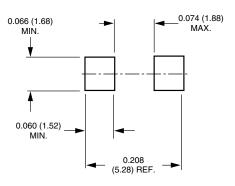


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout





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